MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

# **TPC6010-H**

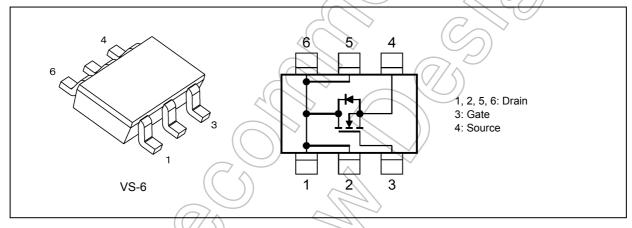
### 1. Applications

- High-Efficiency DC-DC Converters
- Notebook PCs
- Mobile Handsets

#### 2. Features

- (1) Small, thin package
- (2) High-speed switching
- (3) Small gate charge:  $Q_{SW} = 2.7 \text{ nC(typ.)}$
- (4) Low drain-source on-resistance:  $R_{DS(ON)} = 43m\Omega$  (typ.) (V<sub>GS</sub> = 4.5 V).
- (5) Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 60 \ V)$
- (6) Enhancement mode:  $V_{th} = 1.3$  to 2.3 V ( $V_{DS} = 10$  V,  $I_D = 0.1$  mA)

#### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	$\bigcirc$	Symbol	Rating	Unit
Drain-source voltage	$\geq$	V <sub>DSS</sub>	60	V
Gate-source voltage		V <sub>GSS</sub>	±20	
Drain current (DC)	(Note 1)	Ι <sub>D</sub>	6.1	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	24.4	
Power dissipation (t = 5 s)	(Note 2)	PD	2.2	W
Power dissipation $(t \neq 5 s)$	(Note 3)	PD	0.7	W
Single-pulse avalanche energy	(Note 4)	E <sub>AS</sub>	5.37	mJ
Avalanche current		I <sub>AR</sub>	6.1	Α
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2010-02

### 5. Thermal Characteristics

Characteristic	cs		Symbol	Max	Unit
Channel-to-ambient thermal resistance	(t = 5 s)	(Note 2)	R <sub>th(ch-a)</sub>	56.8	°C/W
Channel-to-ambient thermal resistance	(t = 5 s)	(Note 3)	R <sub>th(ch-a)</sub>	178	°C/W
Note 1: Ensure that the channel temperature do Note 2: Device mounted on a glass-epoxy board Note 3: Device mounted on a glass-epoxy board Note 4: $V_{DD}$ = 24 V, $T_{ch}$ = 25°C (initial), L = 0.2 r	d (a), Figure 5.1 d (b), Figure 5.2		<b>O</b>		
FR-4 25.4 × 25.4 × 0.8 (Unit: mm)			> 25.4 × 2	R-4 5.4 × 0.8 Jnit: mm)	
Fig. 5.1 Device Mounted on a Glass-E Board (a)	poxy Fig.t		ounted on a oard (b)	Glass-Ep	юху
Note: This transistor is sensitive to electrostati	c discharge and sho	ould be handled	with care.		

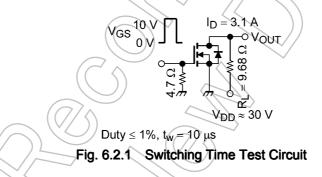
#### 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	_	_	±0.1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V	$\mathbb{Z}$	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	60		_	V
	V <sub>(BR)DSX</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -20 V	45		_	
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.1 mA	1.3	2_	2.3	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 3.1 A	/A	43	63	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.1 A	$\sum$	39	59	

### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz		640	830	pF
Reverse transfer capacitance	C <sub>rss</sub>		((	24	38	
Output capacitance	C <sub>oss</sub>		K	- (95/)	) —	
Gate resistance	r <sub>g</sub>	$V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 5 MHz	$\sim$	3.1	4.7	Ω
Switching time (rise time)	tr	See Figure 6.2.1.		2.4	_	ns
Switching time (turn-on time)	t <sub>on</sub>			8.2	_	
Switching time (fall time)	t <sub>f</sub>			3.2	_	
Switching time (turn-off time)	t <sub>off</sub>		U –	18	_	



### 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

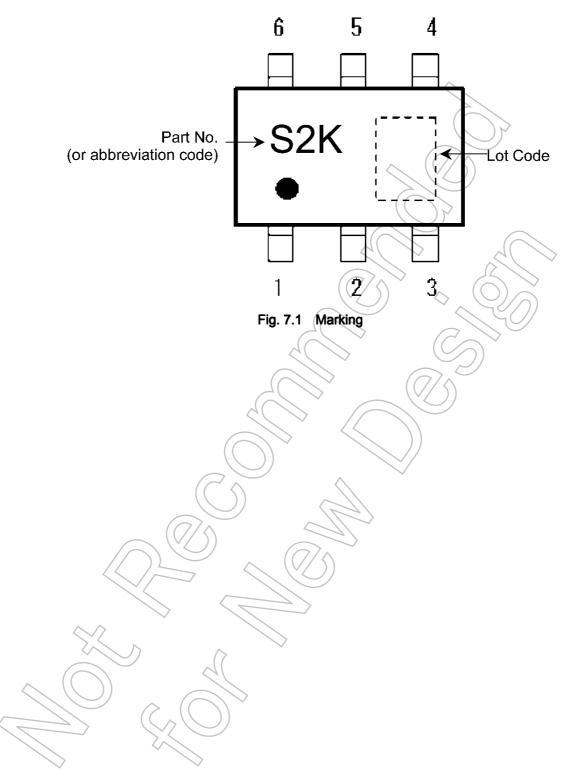
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD}\approx 48~V,~V_{GS}$ = 10 V, $I_{D}$ = 6.1 A	_	12	_	nC
gate-drain)		$V_{DD} \approx 48$ V, $V_{GS}$ = 5 V, $I_D$ = 6.1 A		6.5	_	
Gate-source charge 1	Q <sub>gs1</sub>	$V_{DD} \approx 48$ V, $V_{GS}$ = 10 V, $I_D$ = 6.1 A	_	2.9	—	
Gate-drain charge	Q <sub>gd</sub>		_	1.9	_	
Gate switch charge	Q <sub>SW</sub>			2.7		

### 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

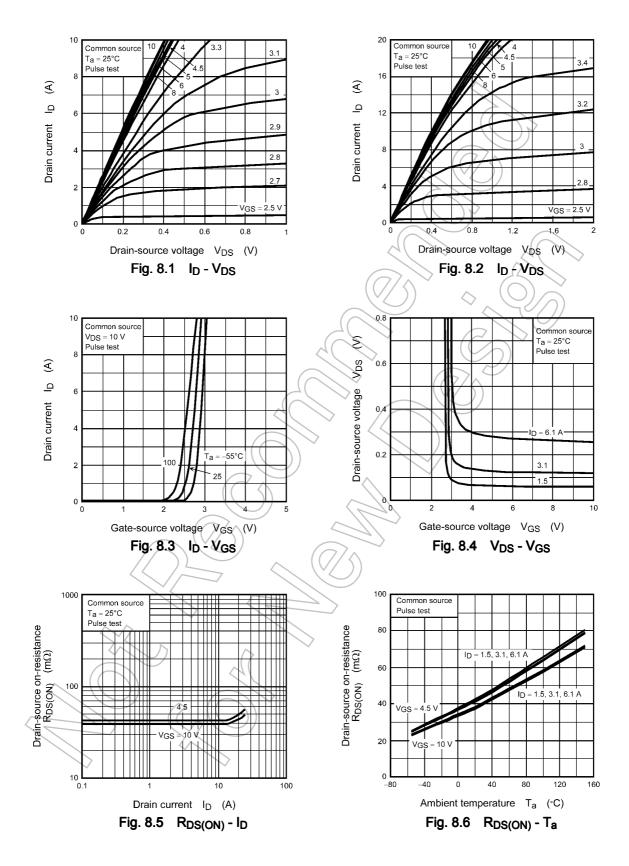
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 5	I <sub>DRP</sub>	—	_	_	24.4	А
Diode forward voltage	V <sub>DSF</sub>	I <sub>DR</sub> = 6.1 A, V <sub>GS</sub> = 0 V	_	_	-1.2	V

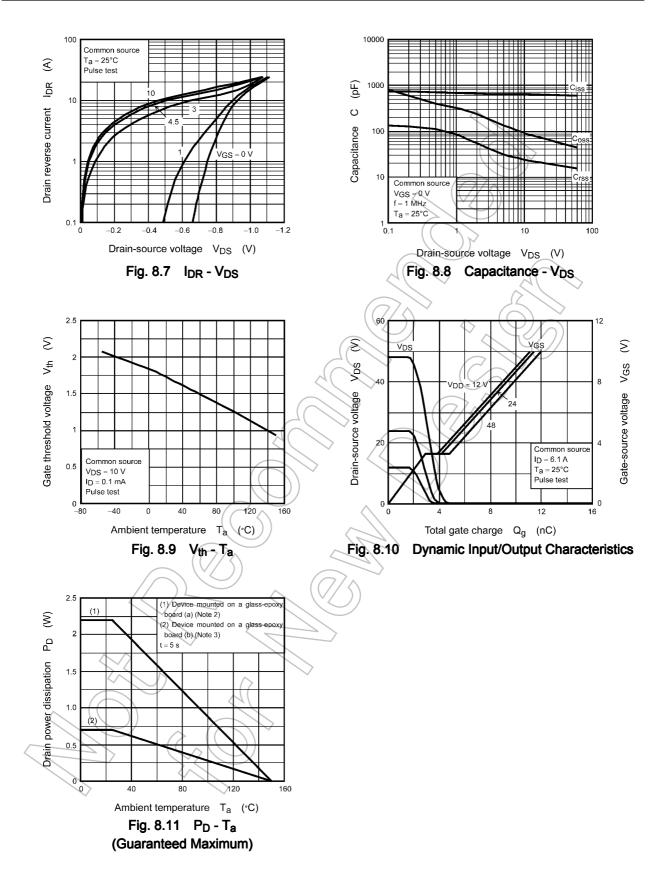
Note 5: Ensure that the channel temperature does not exceed 150°C.

7. Marking

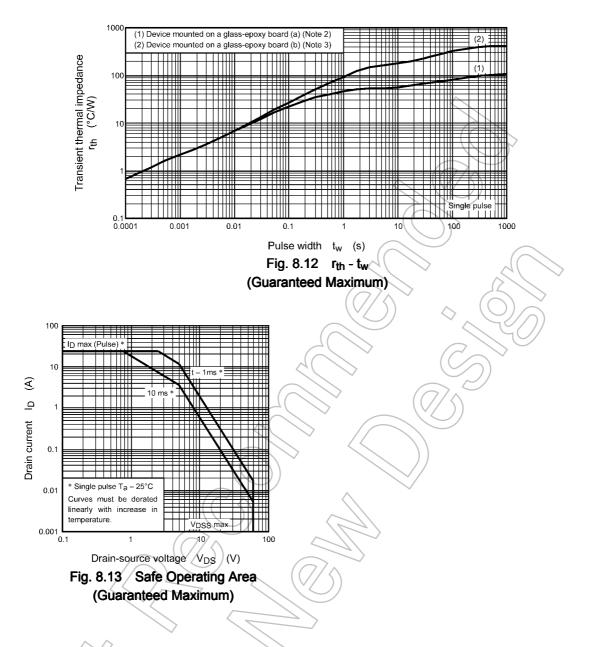


### 8. Characteristics Curves (Note)







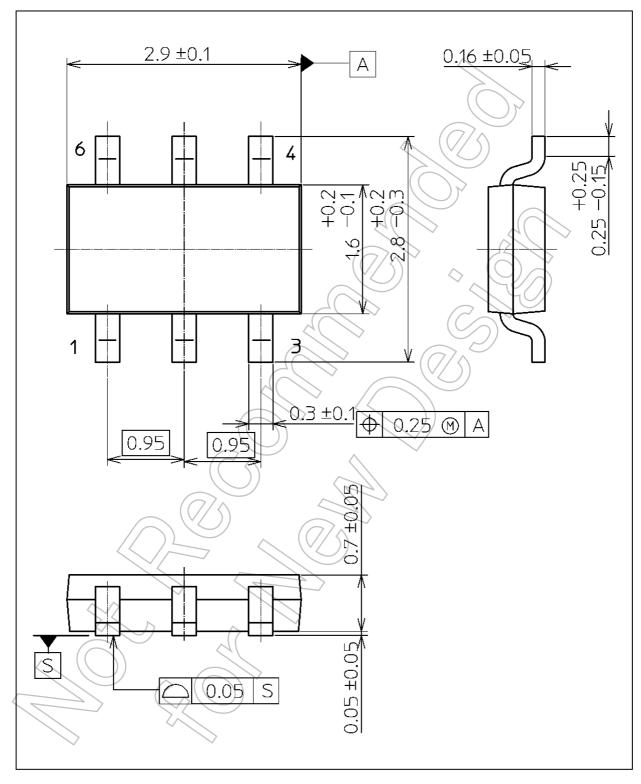


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### **Package Dimensions**

Unit: mm



#### Weight: 0.011 g (typ.)

	Package Name(s)
TOSHIBA: 2-3T1S	
Nickname: VS-6	

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